

32 kHz MEMS Oscillators / 32 kHz TC-MO -μPower

MO1532/MO1552/MO1630/MO1566/MO1568



■Features

- Fixed 32.768 kHz
- Ultra-low power
- Internal filtering eliminates external Vdd bypass cap

■ Applications

- Mobile Phones, Tablets
- Health and wellness monitors, Fitness Watches
- Pulse-per- second timekeeping, RTC reference clock
- Battery Management Timekeeping





RoHS Compliant

Model	Output Frequency (kHz)	Frequency Tolerance (×10 ⁻⁶)	Supply Voltage (V)	Current Consumption (µA Typ.)	Size (mm)	Output
MO1532		±10 room; 75, 100 over temp.	+1.2 to +3.63	+0.90	1.5×0.8×0.6 (CSP)	NanoDrive™ LVCMOS
MO1552 TC-MO	TC-MO 1001630 to +105°C 101566 er TC-MO 1001568	±5, ±10, ±20 over temp.	+1.5 to +3.63	+0.99	1.5 × 0.6 × 0.6 (CSP)	
MO1630 -40 to +105℃		±20 room; ±75,100,150 over temp.	+1.5 (0 +3.63	+1.00	2.0×1.2×0.6 (QFN) 2.9×2.8×1.3 (SOT23-5)	
MO1566 Super TC-MO		±3, 5 all inclusive	+1.8	+4.5	1.5×0.8×0.6 (CSP)	LVCMOS
MO1568 Super TC-MO		±5 all inclusive After Overmold/Underfill	1 +1.8			

■ Standard Specification (MO1532)

Item	Legend	Min.	Тур.	Max.	Unit	Condition			
Output Frequency Range	Fout	32.768		kHz					
Supply Voltage	Vdd	+1.2	-	+3.63	V	$T_A = -10^{\circ}C$ to $+70^{\circ}C$			
		+1.5	-	+3.63		$T_A = -40^{\circ} \text{C}$ to $+85^{\circ} \text{C}$			
Operating Temperature Range	T_use	-10 to +70 / -40 to +85			$^{\circ}$				
	F_stab	-	ı	+75	×10⁻ ⁶	$T_A = -10^{\circ}$ C to $+70^{\circ}$ C, Vdd: $+1.5$ V to $+3.63$ V			
Frequency Stability [1]		-	-	+100		$T_A = -40^{\circ}C$ to $+85^{\circ}C$, Vdd: $+1.5V$ to $+3.63V$			
		-	-	+250		$T_A = -10^{\circ}C$ to $+70^{\circ}C$, Vdd: $+1.2V$ to $+1.5V$			
	F_tol	-	-	+10	×10 ⁻⁶	$T_A = +25^{\circ}$ C, post reflow, Vdd: +1.5V to +3.63V			
Frequency Tolerance [2]		-	-	+20		$T_A = +25^{\circ}$ C, post reflow with board-level underfill, Vdd: +1.5V to +3.63V			
First Year Aging	F_aging1	-1.0	-	+1.0	×10 ⁻⁶	T _A = +25℃			
	Idd	-	+0.9	-	μΑ	$T_A = +25^{\circ}C$, Vdd: +1.8V. No load			
Core Operating Current [3]		-	-	+1.3		$T_A = -10^{\circ}$ C to $+70^{\circ}$ C, Vdd max: $+3.63$ V. No load			
		1	-	+1.4		$T_A = -40^{\circ}$ C to $+85^{\circ}$ C, Vdd max: $+3.63$ V. No load			
Start-up Time [4]	T_start	-	180	300	ms	$T_A = -40^{\circ}C \le T_A \le +50^{\circ}C$, valid output			
		-	-	450		$T_A = +50^{\circ} C < T_A \le +85^{\circ} C$, valid output			
LVCMOS Output Option, TA = -40°C to +85°C, typical values are at $T_A = +25$ °C									
Duty Cycle	DC	48	-	52	%				
Output Low Voltage	V _{OL}	-	-	Vdd×0.1	V	Vdd: $+1.5V$ to $+3.63V$, $I_{OL} = +10 \mu A$, 15 pF			
Output High Voltage	V _{OH}	Vdd×0.9	ı	-	V	Vdd: +1.5V to +3.63V, $I_{OH} = -10 \mu A$, 15 pF			
Rise and Fall Time	Tr, Tf	-	100	200	ns	10 to 90% (Vdd), 15 pF load, Vdd = +1.5V to +3.63V			
Rise and rall time		-	-	50		10 to 90% (Vdd), 5 pF load, Vdd ≥ +1.62V			
Packing Unit	1000pcs./reel (φ180) or 3000pcs./reel (φ180)								

 ^{[1].} Measured peak-to-peak. Inclusive of Initial Tolerance at +25°C, and variations over operating temperature, rated power supply voltage and load. Stability is specified for two operating voltage ranges. Stability progressively degrades with supply voltage below +1.5V.
 [2]. Measured peak-to-peak. Tested with Keysight 53132A frequency counter. Due to the low operating frequency, the gate time must be ≥100

ms to ensure an accurate frequency measurement.

 ^{[3].} Core operating current does not include output driver operating current or load current. To derive total operating current (no load), add core operating current + (+0.065 μA/V)×(output voltage swing).
 [4]. Measured from the time Vdd reaches +1.5V.